NSN 5961-01-369-8442

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-369-8442 **Inclosure Material:** Metal **Overall Length:** 0.800 inches **Overall Height:** 0.210 inches **Overall Width:** 0.250 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Emitter **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 32.0 collector to emitter reverse voltage and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 milliamperes base current, dc minor **Power Rating Per Characteristic:** 4.3 watts any acceptable absolute **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Flange and terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-01-369-8442 Transistor - Page 2 of 2



Fiig:

A110a0